

19-0270: Rev 0; 8/94

**MAXIM**

## Precision, 16-Channel/Dual 8-Channel, High-Performance, CMOS Analog Multiplexers

### General Description

The MAX306/MAX307 precision, monolithic, CMOS analog multiplexers (muxes) offer low on-resistance (less than 100Ω), which is matched to within 5Ω between channels and remains flat over the specified analog signal range (7Ω max). They also offer low leakage over temperature ( $I_{NO(OFF)}$ ) less than 2.5nA at +85°C and fast switching speeds ( $t_{TRANS}$  less than 250ns). The MAX306 is a single-ended 1-of-16 device, and the MAX307 is a differential 2-of-8 device.

The MAX306/MAX307 are fabricated with Maxim's improved 44V silicon-gate process. Design improvements yield extremely low charge injection (less than 10pC) and guarantee electrostatic discharge (ESD) protection greater than 2000V.

These muxes operate with a single +4.5V to +30V supply, or bipolar ±4.5V to ±20V supplies, while retaining TTL/CMOS-logic input compatibility and fast switching. CMOS inputs provide reduced input loading. These improved parts are plug-in upgrades for the industry-standard DG406, DG407, DG506A, and DG507A.

### Applications

- Sample-and-Hold Circuits
- Test Equipment
- Heads-Up Displays
- Guidance and Control Systems
- Military Radios
- Communications Systems
- Battery-Operated Systems
- PBX, PABX
- Audio Signal Routing

### Features

- ♦ Guaranteed On-Resistance Match Between Channels, <5Ω Max
- ♦ Low On-Resistance, <100Ω Max
- ♦ Guaranteed Flat On-Resistance over Specified Signal Range, 7Ω Max
- ♦ Guaranteed Charge Injection, <10pC
- ♦  $I_{NO(OFF)}$  Leakage <2.5nA at +85°C
- ♦  $I_{COM(OFF)}$  Leakage <20nA at +85°C
- ♦ ESD Protection >2000V
- ♦ Plug-In Upgrade for Industry-Standard DG406/DG407/DG506A/DG507A
- ♦ Single-Supply Operation (+4.5V to +30V) Bipolar-Supply Operation (±4.5V to ±20V)
- ♦ Low Power Consumption, <1.25mW
- ♦ Rail-to-Rail Signal Handling
- ♦ TTL/CMOS-Logic Compatible

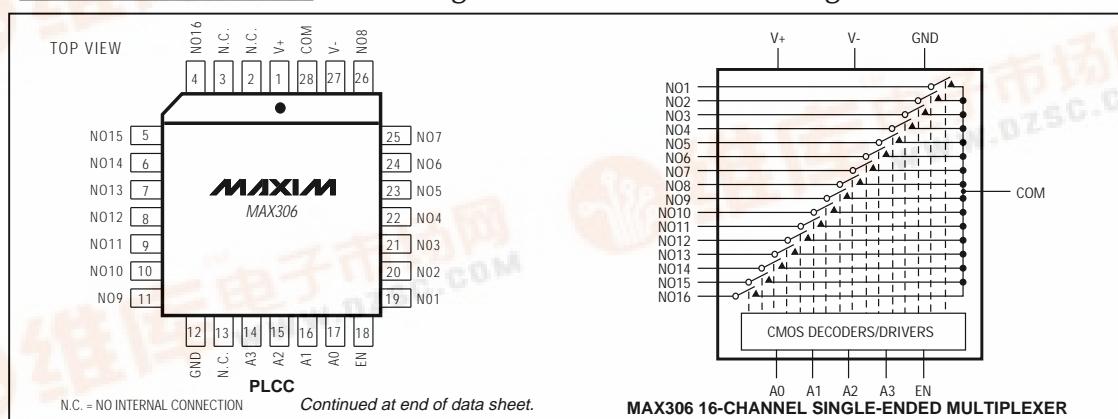
### Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MAX306CPI	0°C to +70°C	28 Plastic DIP
MAX306CWI	0°C to +70°C	28 Wide SO
MAX306C/D	0°C to +70°C	Dice*
MAX306EPI	-40°C to +85°C	28 Plastic DIP
MAX306EWI	-40°C to +85°C	28 Wide SO
MAX306EQI	-40°C to +85°C	28 PLCC
MAX306MJI	-55°C to +125°C	28 CERDIP

*Ordering Information continued at end of data sheet.*

\* Contact factory for dice specifications.

### Pin Configurations/Functional Diagrams/Truth Tables

**MAXIM**

Call toll free 1-800-998-8800 for free samples or literature.

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## ABSOLUTE MAXIMUM RATINGS

Voltage Referenced to V-	
V+	-0.3V, 44V
GND	-0.3V, 25V
Digital Inputs, NO, COM (Note 1)	(V- - 2V) to (V+ + 2V) or 30mA (whichever occurs first)
Continuous Current (any terminal)	30mA
Peak Current, NO or COM (pulsed at 1ms, 10% duty cycle max)	100mA
Continuous Power Dissipation ( $T_A = +70^\circ\text{C}$ )	727mW

Wide SO (derate 12.50mW/ $^\circ\text{C}$ above $+70^\circ\text{C}$ )	1000mW
PLCC (derate 10.53mW/ $^\circ\text{C}$ above $+70^\circ\text{C}$ )	842mW
CERDIP (derate 16.67mW/ $^\circ\text{C}$ above $+70^\circ\text{C}$ )	1333mW
Operating Temperature Ranges	
MAX30_C_	0°C to $+70^\circ\text{C}$
MAX30_E_	-40°C to $+85^\circ\text{C}$
MAX30_MJ1	-55°C to $+125^\circ\text{C}$
Storage Temperature Range	-65°C to $+150^\circ\text{C}$
Lead Temperature (soldering, 10sec)	+300°C

**Note 1:** Signals on NO, COM, A0, A1, A2, A3, or EN exceeding V+ or V- are clamped by internal diodes. Limit forward current to maximum current ratings.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ELECTRICAL CHARACTERISTICS—Dual Supplies

( $V_+ = +15\text{V}$ ,  $V_- = -15\text{V}$ , GND = 0V, VAH =  $+2.4\text{V}$ , VAL =  $+0.8\text{V}$ ,  $T_A = \text{TMIN}$  to  $\text{TMAX}$ , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS			MIN	TYP	MAX	(Note 2)	UNITS
<b>SWITCH</b>									
Analog Signal Range	$V_{NO}, V_{COM}$	(Note 3)			-15	15			V
On-Resistance	$R_{ON}$	$I_{NO} = -1.0\text{mA}$ , $V_{COM} = \pm 10\text{V}$	$T_A = +25^\circ\text{C}$		60	100		$\Omega$	
			$T_A = \text{TMIN}$ to $\text{TMAX}$			125			
On-Resistance Matching Between Channels	$\Delta R_{ON}$	$I_{NO} = -1.0\text{mA}$ , $V_{COM} = \pm 10\text{V}$ (Note 4)	$T_A = +25^\circ\text{C}$		1.5	5		$\Omega$	
			$T_A = \text{TMIN}$ to $\text{TMAX}$			8			
On-Resistance Flatness	$R_{FLAT}$	$I_{NO} = -1.0\text{mA}$ , $V_{COM} = \pm 5\text{V}$ or 0V	$T_A = +25^\circ\text{C}$		1.8	7		$\Omega$	
			$T_A = \text{TMIN}$ to $\text{TMAX}$			10			
NO-Off Leakage Current (Note 5)	$I_{NO(OFF)}$	$V_{COM} = \mp 10\text{V}$ , $V_{NO} = \pm 10\text{V}$ , $V_{EN} = 0\text{V}$	$T_A = +25^\circ\text{C}$		-0.5	0.01	0.5		nA
			$T_A = \text{TMIN}$ to $\text{TMAX}$	C, E	-2.5	2.5			
					-5.0	5.0			
COM-Off Leakage Current (Note 5)	$I_{COM(OFF)}$	$V_{NO} = \pm 10\text{V}$ , $V_{COM} = \mp 10\text{V}$ , $V_{EN} = 0\text{V}$	$T_A = +25^\circ\text{C}$		-0.75	0.02	0.75		nA
			$T_A = \text{TMIN}$ to $\text{TMAX}$	C, E	-20	20			
					-40	40			
		$V_{NO} = \mp 10\text{V}$ , $V_{COM} = \pm 10\text{V}$ , $V_{EN} = 0\text{V}$	$T_A = +25^\circ\text{C}$		-0.75	0.02	0.75		
			$T_A = \text{TMIN}$ to $\text{TMAX}$	C, E	-10	10			
					-20	20			
COM-On Leakage Current (Note 5)	$I_{COM(ON)}$	$V_{COM} = \pm 10\text{V}$ , $V_{NO} = \pm 10\text{V}$ , sequence each switch on	$T_A = +25^\circ\text{C}$		-0.75	0.02	0.75		nA
			$T_A = \text{TMIN}$ to $\text{TMAX}$	C, E	-25	25			
					-50	50			
		$V_{COM} = \pm 10\text{V}$ , $V_{NO} = \pm 10\text{V}$ , sequence each switch on	$T_A = +25^\circ\text{C}$		-0.75	0.02	0.75		
			$T_A = \text{TMIN}$ to $\text{TMAX}$	C, E	-12.5	12.5			
					-25	25			

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## ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

( $V_+ = +15V$ ,  $V_- = -15V$ ,  $GND = 0V$ ,  $V_{AH} = +2.4V$ ,  $V_{AL} = +0.8V$ ,  $T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
<b>INPUT</b>							
Input Current with Input Voltage High	$I_{AH}$	$V_A = 2.4V$ or $15V$		-1.0	1.0	1.0	$\mu A$
Input Current with Input Voltage Low	$I_{AL}$	$V_{EN} = 0V$ or $2.4V$ , $V_A = 0V$		-1.0	1.0	1.0	$\mu A$
<b>SUPPLY</b>							
Power-Supply Range				$\pm 4.5$	$\pm 20$	$\pm 20$	V
Positive Supply Current	$I_+$	$V_{EN} = V_A = 0V$ or $4.5V$		$T_A = +25^\circ C$	16	30	$\mu A$
		$V_{EN} = 2.4V$ , $V_{A(ALL)} = 0V$ or $2.4V$		$T_A = T_{MIN}$ to $T_{MAX}$		75	
Negative Supply Current	$I_-$	$V_{EN} = 2.4V$ , $V_{A(ALL)} = 0V$ or $2.4V$		$T_A = +25^\circ C$	0.075	0.5	mA
				$T_A = T_{MIN}$ to $T_{MAX}$		1	
Enable Turn-On Time	$t_{ON(EN)}$			$T_A = +25^\circ C$	-1	1	$\mu A$
				$T_A = T_{MIN}$ to $T_{MAX}$	-10	10	
<b>DYNAMIC</b>							
Transistion Time	$t_{TRANS}$	Figure 2		$T_A = +25^\circ C$	110	300	ns
				$T_A = T_{MIN}$ to $T_{MAX}$		400	
Break-Before-Make Interval	$t_{OPEN}$	Figure 4		$T_A = +25^\circ C$	10	40	ns
Enable Turn-On Time	$t_{ON(EN)}$	Figure 3		$T_A = +25^\circ C$	130	200	ns
				$T_A = T_{MIN}$ to $T_{MAX}$		400	
Enable Turn-Off Time	$t_{OFF(EN)}$	Figure 3		$T_A = +25^\circ C$	55	150	ns
				$T_A = T_{MIN}$ to $T_{MAX}$		300	
Charge Injection (Note 3)	$Q$	$C_L = 1.0nF$ , $V_{NO} = 0V$ , $R_S = 0\Omega$ , Figure 5		$T_A = +25^\circ C$	2	10	pC
Off Isolation (Note 6)	$V_{ISO}$	$V_{EN} = 0V$ , $R_L = 1k\Omega$ , $f = 100kHz$ , Figure 6		$T_A = +25^\circ C$	-69		dB
Crosstalk Between Channels	$V_{CT}$	$V_{EN} = 2.4V$ , $f = 100kHz$ , $V_{GEN} = 1V_{P.P.}$ , $R_L = 1k\Omega$ , Figure 7		$T_A = +25^\circ C$	-92		dB
Logic Input Capacitance	$C_{IN}$	$f = 1MHz$		$T_A = +25^\circ C$	8		pF
NO-Off Capacitance	$C_{NO(OFF)}$	$f = 1MHz$ , $V_{EN} = V_{NO} = 0V$ , Figure 8		$T_A = +25^\circ C$	8		pF
COM-Off Capacitance	$C_{COM(OFF)}$	$f = 1MHz$ , $V_{EN} = 0.8V$ , $V_{COM} = 0V$ , Figure 8	MAX306	$T_A = +25^\circ C$	130		pF
			MAX307		65		
COM-On Capacitance	$C_{COM(ON)}$	$f = 1MHz$ , $V_{EN} = 2.4V$ , $V_{COM} = 0V$ , Figure 8	MAX306	$T_A = +25^\circ C$	140		pF
			MAX307		70		

# Precision, 16-Channel/Dual 8-Channel, High-Performance, CMOS Analog Multiplexers

## ELECTRICAL CHARACTERISTICS—Single Supply

(V<sub>+</sub> = +12V, V<sub>-</sub> = 0V, GND = 0V, V<sub>AH</sub> = +2.4V, V<sub>AL</sub> = +0.8V, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	(Note 2)	UNITS
<b>SWITCH</b>								
Analog Signal Range	V <sub>NO</sub> , V <sub>COM</sub>	(Note 3)		0	12		V	
On-Resistance	R <sub>ON</sub>	I <sub>NO</sub> = -1.0mA V <sub>COM</sub> = 3V or 10V	T <sub>A</sub> = +25°C	120	175		Ω	
<b>DYNAMIC</b>								
Transition Time (Note 3)	t <sub>TRANS</sub>	V <sub>NO1</sub> = 8V, V <sub>NO8</sub> = 0V, V <sub>IN</sub> = 2.4V, Figure 1	T <sub>A</sub> = +25°C	130	450		ns	
Enable Turn-On Time (Note 3)	t <sub>ON(EN)</sub>	V <sub>INH</sub> = 2.4V, V <sub>INL</sub> = 0V, V <sub>NO1</sub> = 5V, Figure 3	T <sub>A</sub> = +25°C	105	600		ns	
Enable Turn-Off Time (Note 3)	t <sub>OFF(EN)</sub>	V <sub>INH</sub> = 2.4V, V <sub>INL</sub> = 0V, V <sub>NO1</sub> = 5V, Figure 3	T <sub>A</sub> = +25°C	80	300		ns	
Charge Injection (Note 3)	Q	C <sub>L</sub> = 1.0nF, V <sub>NO</sub> = 0V, R <sub>S</sub> = 0Ω	T <sub>A</sub> = +25°C	2	10		pC	

**Note 2:** The algebraic convention where the most negative value is a minimum and the most positive value a maximum is used in this data sheet.

**Note 3:** Guaranteed by design.

**Note 4:**  $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$ . On-resistance match between channels and flatness are guaranteed only with specified voltages. Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured at the extremes of the specified analog signal range.

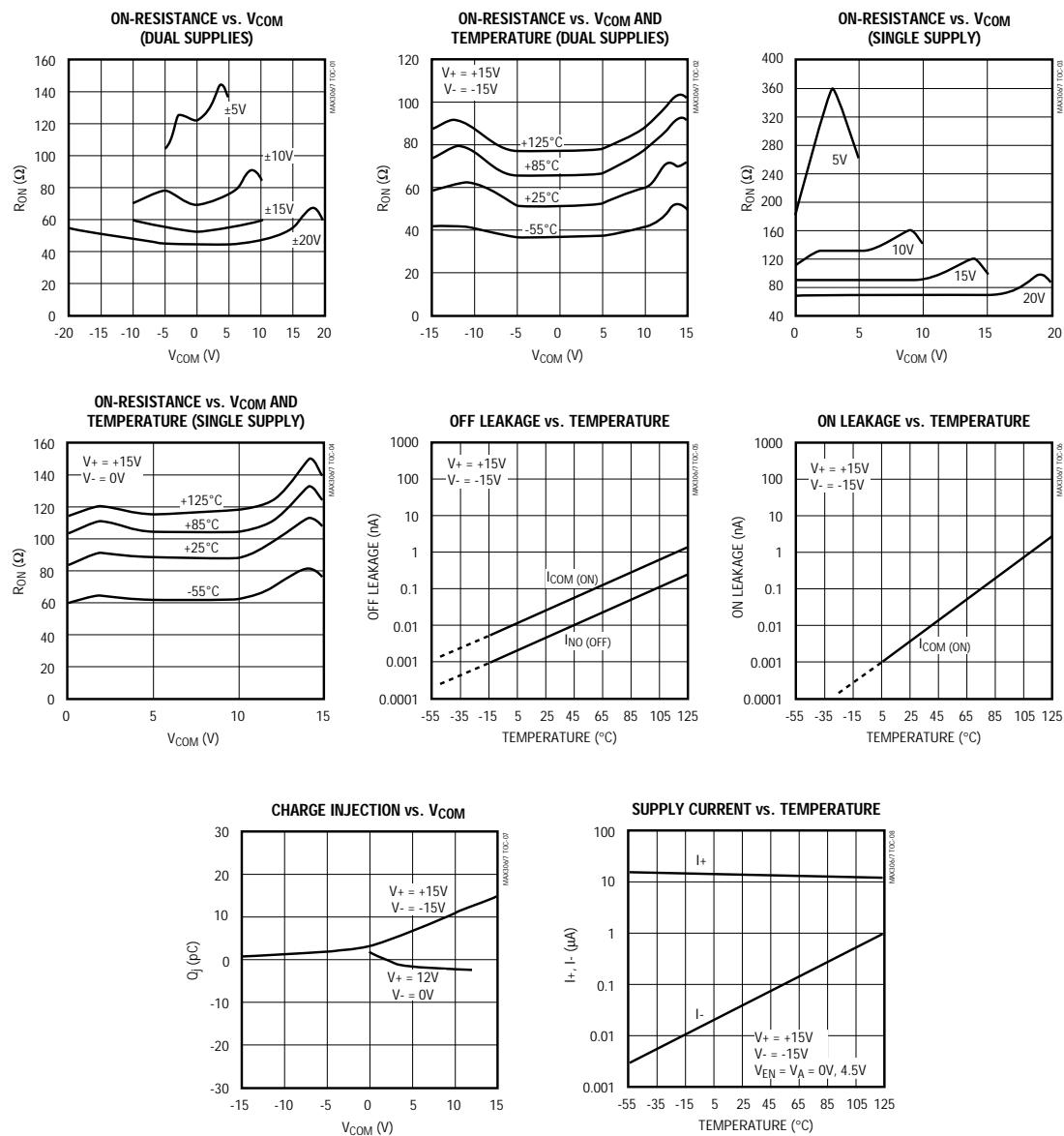
**Note 5:** Leakage parameters are 100% tested at the maximum rated hot temperature and guaranteed by correlation at +25°C.

**Note 6:** Off isolation =  $20\log V_{COM}/V_{NO}$ , where V<sub>COM</sub> = output and V<sub>NO</sub> = input to off switch.

# Precision, 16-Channel/Dual 8-Channel, High-Performance, CMOS Analog Multiplexers

## Typical Operating Characteristics

( $T_A = +25^\circ\text{C}$ , unless otherwise noted.)



# Precision, 16-Channel/Dual 8-Channel, High-Performance, CMOS Analog Multiplexers

## Pin Descriptions

MAX306 PIN	NAME	FUNCTION
1	V+	Positive Supply Voltage Input
2, 3, 13	N.C.	No Internal Connections
4–11	NO16–NO9	Analog Inputs–bidirectional
12	GND	Ground
14–17	A3–A0	Address Inputs
18	EN	Enable Inputs
19–26	NO1–NO8	Analog Inputs–bidirectional
27	V-	Negative Supply Voltage Input
28	COM	Output–bidirectional

MAX307 PIN	NAME	FUNCTION
1	V+	Positive Supply Voltage Input
2	COMB	Output B–bidirectional
3, 13, 14	N.C.	No Internal Connection
4–11	NO8B–NO1B	Analog Inputs–bidirectional
12	GND	Ground
15, 16, 17	A2, A1, A0	Address Inputs
18	EN	Enable Input
19–26	NO1A–NO8A	Analog Inputs–bidirectional
27	V-	Negative Supply Voltage Input
28	COMA	Output A–bidirectional

## Applications Information

### Operation with Supply Voltages Other than $\pm 15V$

Using supply voltages other than  $\pm 15V$  will reduce the analog signal range. The MAX306/MAX307 switches operate with  $\pm 4.5V$  to  $\pm 20V$  bipolar supplies or with a  $+4.5V$  to  $+30V$  single supply; connect V- to GND when operating with a single supply. Also, both device types can operate with unbalanced supplies such as  $+24V$  and  $-5V$ . The *Typical Operating Characteristics* graphs show typical on-resistance with  $20V$ ,  $15V$ ,  $10V$ , and  $5V$  supplies. (Switching times increase by a factor of two or more for operation at  $5V$ .)

### Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings because stresses beyond the listed ratings may cause permanent damage to the devices. Always sequence V+ on first, then V-, followed by either the logic inputs, NO, or COM. If power-supply sequencing is not possible, add two small signal diodes in series with supply pins for overvoltage protection (Figure 1). Adding diodes reduces the analog

signal range to 1V above V+ and 1V below V-, but low switch resistance and low leakage characteristics are unaffected. Device operation is unchanged, and the difference between V+ and V- should not exceed  $+44V$ .

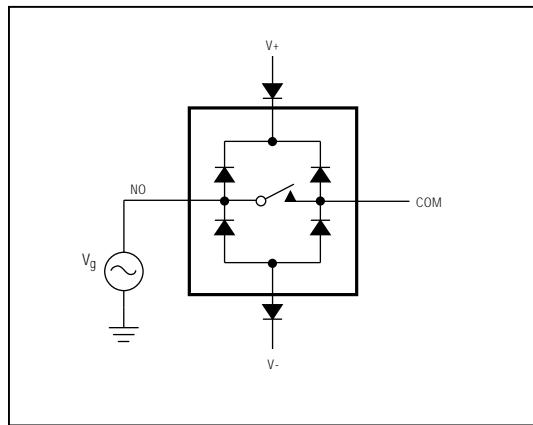


Figure 1. Overvoltage Protection Using External Blocking Diodes

## Precision, 16-Channel/Dual 8-Channel, High-Performance, CMOS Analog Multiplexers

### Test Circuits/Timing Diagrams

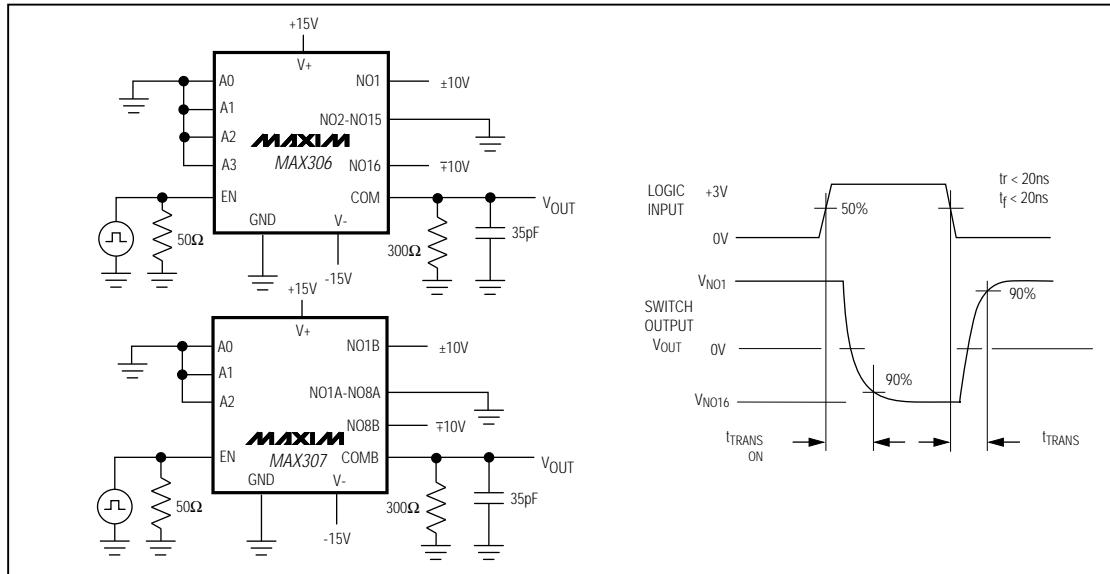


Figure 2. Transition Time

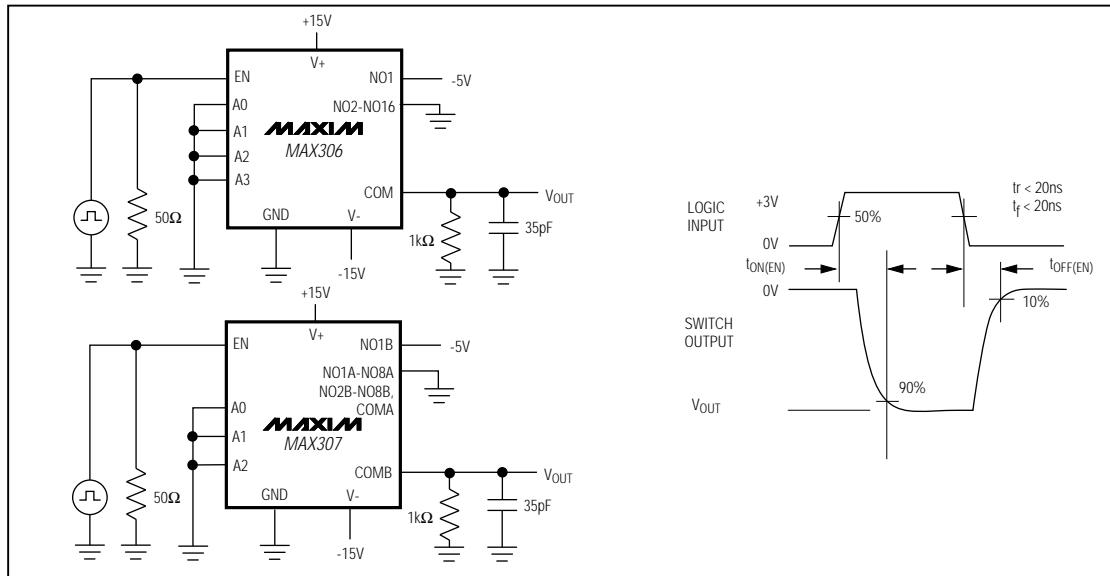


Figure 3. Enable Switching Time

## Precision, 16-Channel/Dual 8-Channel, High-Performance, CMOS Analog Multiplexers

### Test Circuits/Timing Diagrams (continued)

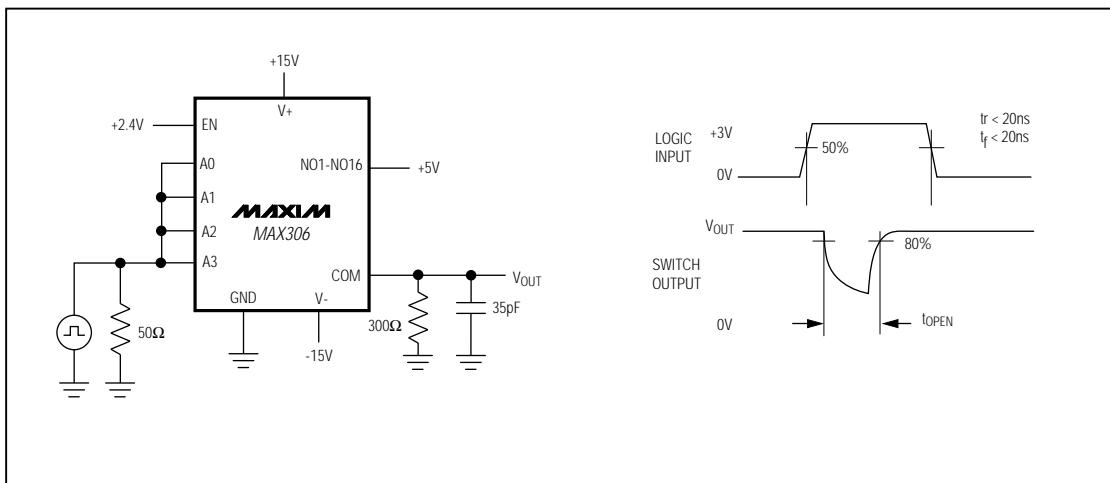


Figure 4. Break-Before-Make Interval

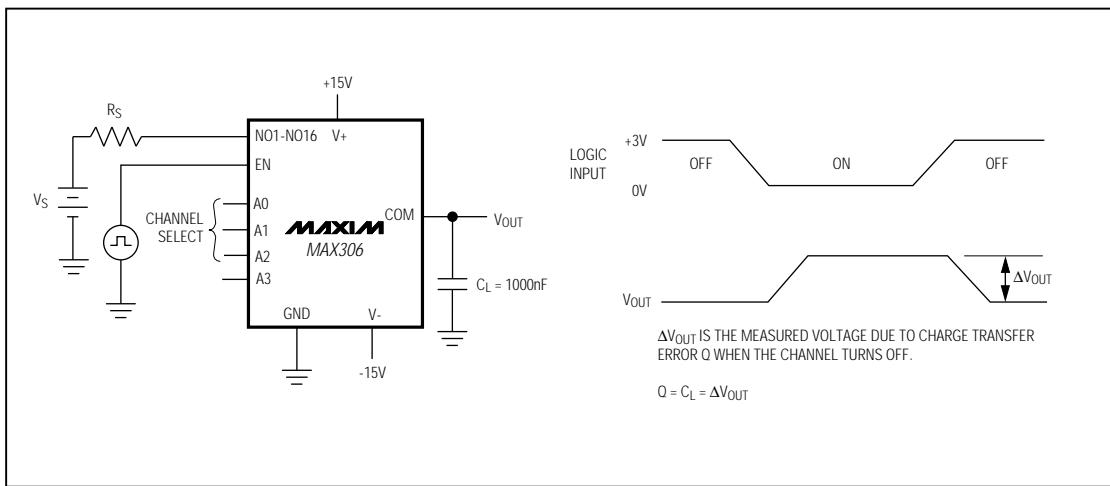


Figure 5. Charge Injection

## Precision, 16-Channel/Dual 8-Channel, High-Performance, CMOS Analog Multiplexers

### Test Circuits/Timing Diagrams (continued)

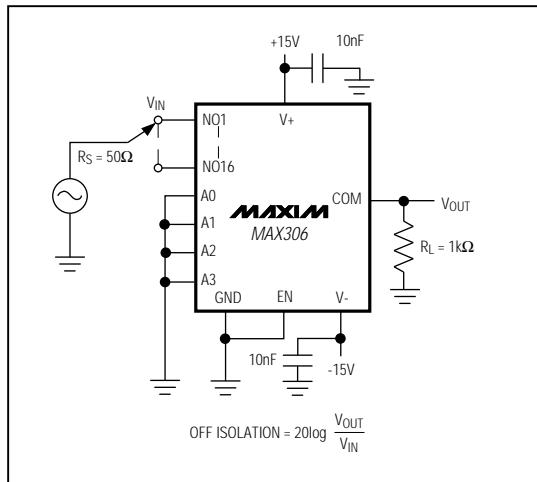


Figure 6. Off Isolation

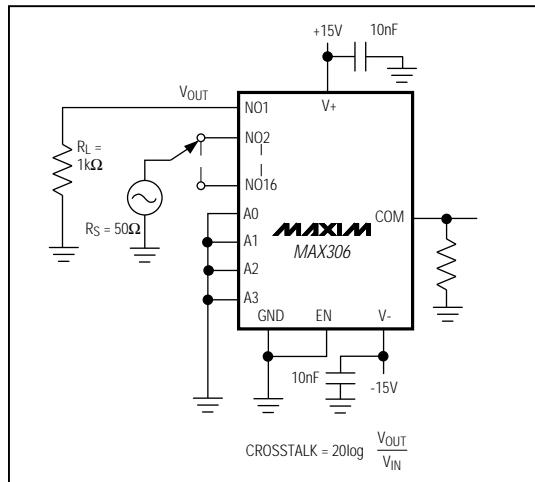


Figure 7. Crosstalk

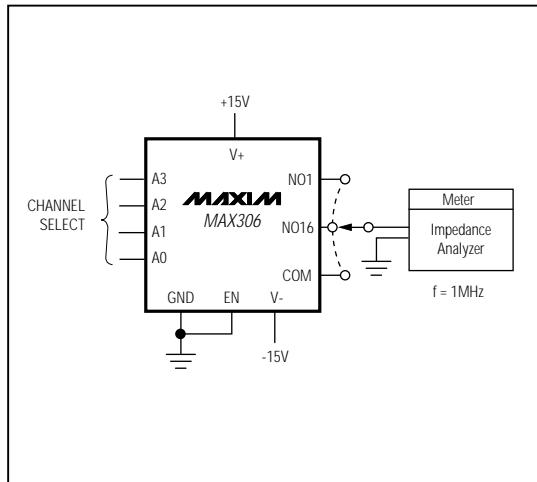
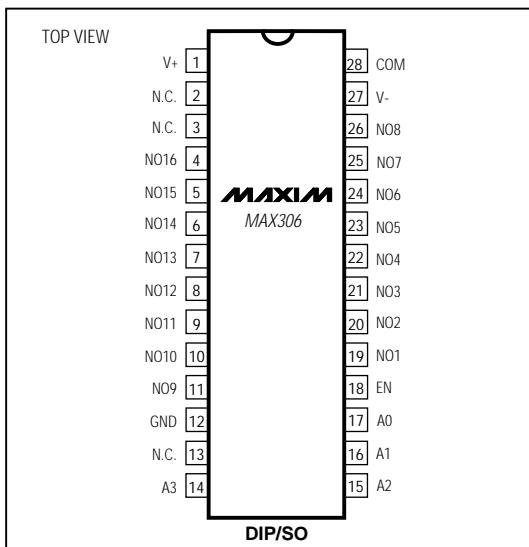


Figure 8. NO/COM Capacitance

*Precision, 16-Channel/Dual 8-Channel,  
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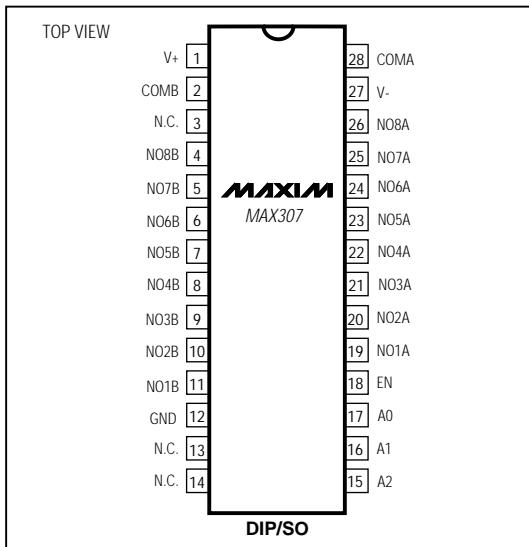
Pin Configurations/Functional Diagrams/Truth Tables (continued)



A3	A2	A1	A0	EN	ON Switch
X	X	X	X	0	None
0	0	0	0	1	1
0	0	0	1	1	2
0	0	1	0	1	3
0	0	1	1	1	4
0	1	0	0	1	5
0	1	0	1	1	6
0	1	1	0	1	7
0	1	1	1	1	8
1	0	0	0	1	9
1	0	0	1	1	10
1	0	1	0	1	11
1	0	1	1	1	12
1	1	0	0	1	13
1	1	0	1	1	14
1	1	1	0	1	15
1	1	1	1	1	16

MAX306

LOGIC "0"  $V_{AL} \leq 0.8V$ , LOGIC "1" =  $V_{AH} \geq 2.4V$



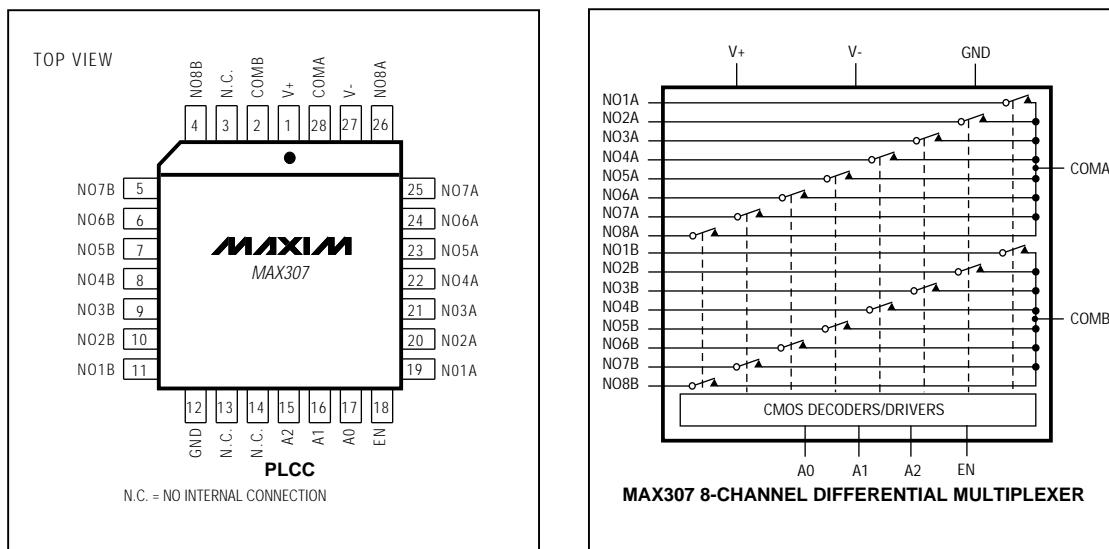
A2	A1	A0	EN	ON Switch
X	X	X	0	None
0	0	0	1	1
0	0	1	1	2
0	1	0	1	3
0	1	1	1	4
1	0	0	1	5
1	0	1	1	6
1	1	0	1	7
1	1	1	1	8

MAX307

LOGIC "0"  $V_{AL} \leq 0.8V$ , LOGIC "1" =  $V_{AH} \geq 2.4V$

## Precision, 16-Channel/Dual 8-Channel, High-Performance, CMOS Analog Multiplexers

Pin Configurations/Functional Diagrams/Truth Tables (continued)



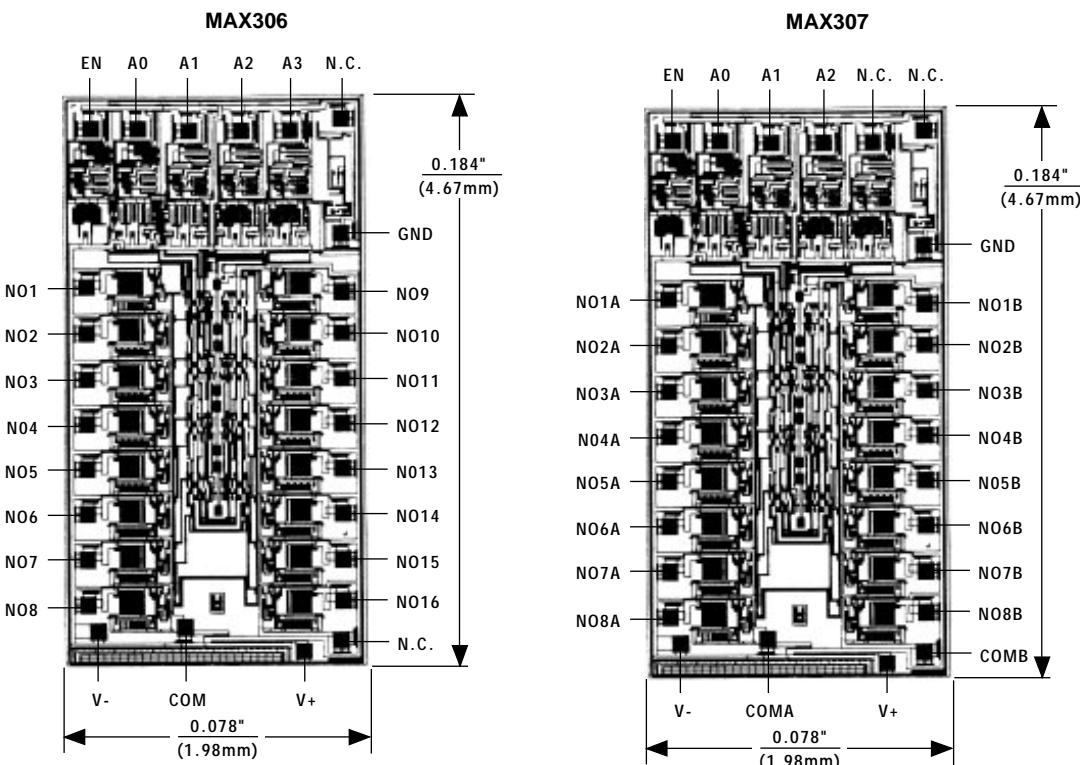
Ordering Information (continued)

PART	TEMP. RANGE	PIN-PACKAGE
<b>MAX307CPI</b>	0°C to +70°C	28 Plastic DIP
MAX307CWI	0°C to +70°C	28 Wide SO
MAX307C/D	0°C to +70°C	Dice*
MAX307EPI	-40°C to +85°C	28 Plastic DIP
MAX307EWI	-40°C to +85°C	28 Wide SO
MAX307EQI	-40°C to +85°C	28 PLCC
MAX307MJI	-55°C to +125°C	28 CERDIP

\* Contact factory for dice specifications.

Precision, 16-Channel/Dual 8-Channel,  
High-Performance, CMOS Analog Multiplexers

Chip Topographies



N.C. = NO INTERNAL CONNECTION

TRANSISTOR COUNT: 269

SUBSTRATE IS INTERNALLY CONNECTED TO V+

TRANSISTOR COUNT: 269

SUBSTRATE IS INTERNALLY CONNECTED TO V+

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

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